



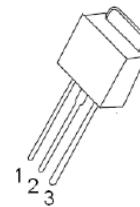
## TO-251-3L Plastic-Encapsulate Transistors

### MJD117 TRANSISTOR (PNP)

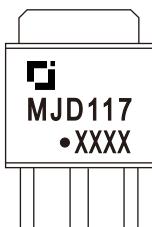
#### FEATURES

- High DC Current Gain
- Low Collector-Emitter Saturation Voltage
- Complementary to MJD117

TO-251-3L

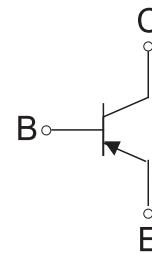


#### MARKING



MJD117=Device code  
Solid dot=Green moldinn compound device,  
if none,the normal device  
XXXX=Code

#### Equivalent Circuit



#### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

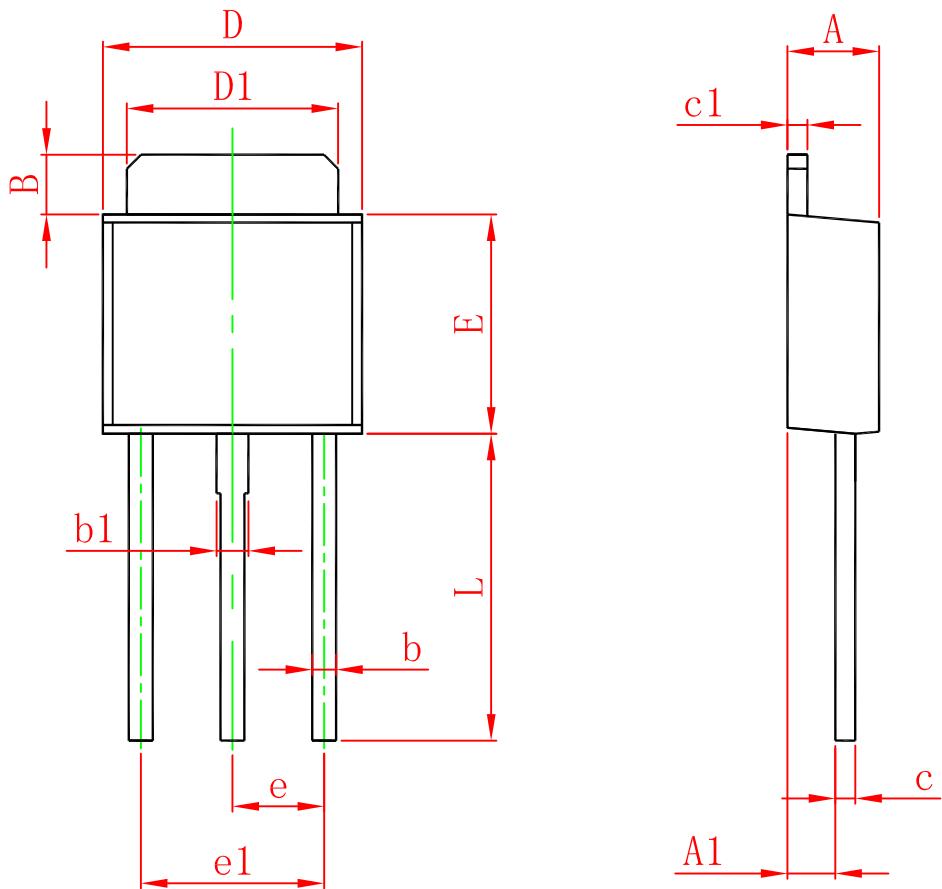
Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-100	V
$V_{CEO}$	Collector-Emitter Voltage	-100	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	-2	A
$P_c$	Collector Power Dissipation	1.5	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	83.3	°C/W
$T_J, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Collector-base breakdown voltage</b>	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-1mA, I <sub>E</sub> =0	-100			V
<b>Collector-emitter breakdown voltage</b>	V <sub>(BR)CEO</sub> <sup>*</sup>	I <sub>C</sub> =-30mA, I <sub>B</sub> =0	-100			V
<b>Emitter-base breakdown voltage</b>	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-5mA, I <sub>C</sub> =0	-5			V
<b>Collector cut-off current</b>	I <sub>CBO</sub>	V <sub>CB</sub> =-80V, I <sub>E</sub> =0			-10	μA
<b>Collector cut-off current</b>	I <sub>CEO</sub>	V <sub>CE</sub> =-80V, I <sub>B</sub> =0			-10	μA
<b>Emitter cut-off current</b>	I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-2	mA
<b>DC current gain</b>	h <sub>FE(1)</sub> <sup>*</sup>	V <sub>CE</sub> =-3V, I <sub>C</sub> =-0.5A	500			
	h <sub>FE(2)</sub> <sup>*</sup>	V <sub>CE</sub> =-3V, I <sub>C</sub> =-2A	1000		12000	
	h <sub>FE(3)</sub> <sup>*</sup>	V <sub>CE</sub> =-3V, I <sub>C</sub> =-4A	200			
<b>Collector-emitter saturation voltage</b>	V <sub>CE(sat)</sub> <sup>*</sup>	I <sub>C</sub> =-2A, I <sub>B</sub> =-8mA			-2	V
		I <sub>C</sub> =-4A, I <sub>B</sub> =-40mA			-3	V
<b>Base-emitter saturation voltage</b>	V <sub>BE(sat)</sub> <sup>*</sup>	I <sub>C</sub> =-4A, I <sub>B</sub> =-40mA			-4	V
<b>Base-emitter voltage</b>	V <sub>BE</sub> <sup>*</sup>	V <sub>CE</sub> =-3V, I <sub>C</sub> =-2A			-2.8	V
<b>Collector output capacitance</b>	C <sub>ob</sub>	V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=0.1MHz			200	pF
<b>Transition frequency</b>	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-0.75A, f=1MHz	25			MHz

\*Pulse test

## TO-251-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	1.050	1.350	0.042	0.054
B	1.350	1.650	0.053	0.065
b	0.500	0.700	0.020	0.028
b1	0.700	0.900	0.028	0.035
c	0.430	0.580	0.017	0.023
c1	0.430	0.580	0.017	0.023
D	6.350	6.650	0.250	0.262
D1	5.200	5.400	0.205	0.213
E	5.400	5.700	0.213	0.224
e	2.300 TYP.		0.091 TYP.	
e1	4.500	4.700	0.177	0.185
L	7.500	7.900	0.295	0.311